

Form 1449*	Atty. Docket No.: 1327.005US1	Serial No. Unknown
INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use several sheets if necessary)	Applicant: Mark Lynn Jenson et al.	
	Filing Date: Herewith	Group: Unknown



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**Examiner Initial	Document Number	Date	Name	Class	Subclass	Filing Date If Appropriate
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*Substitute Disclosure Statement Form (PTO-1449)

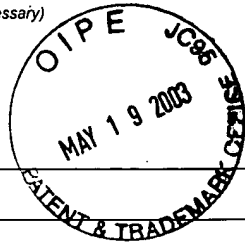
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Application Number	09/815983
Filing Date	March 23, 2001
First Named Inventor	Jenson, Mark
Group Art Unit	1745
Examiner Name	Unknown

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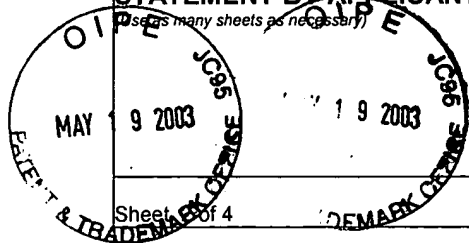
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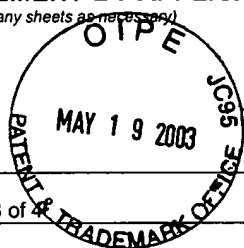
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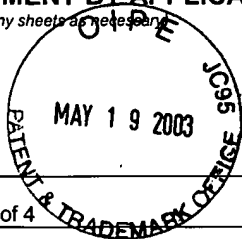
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